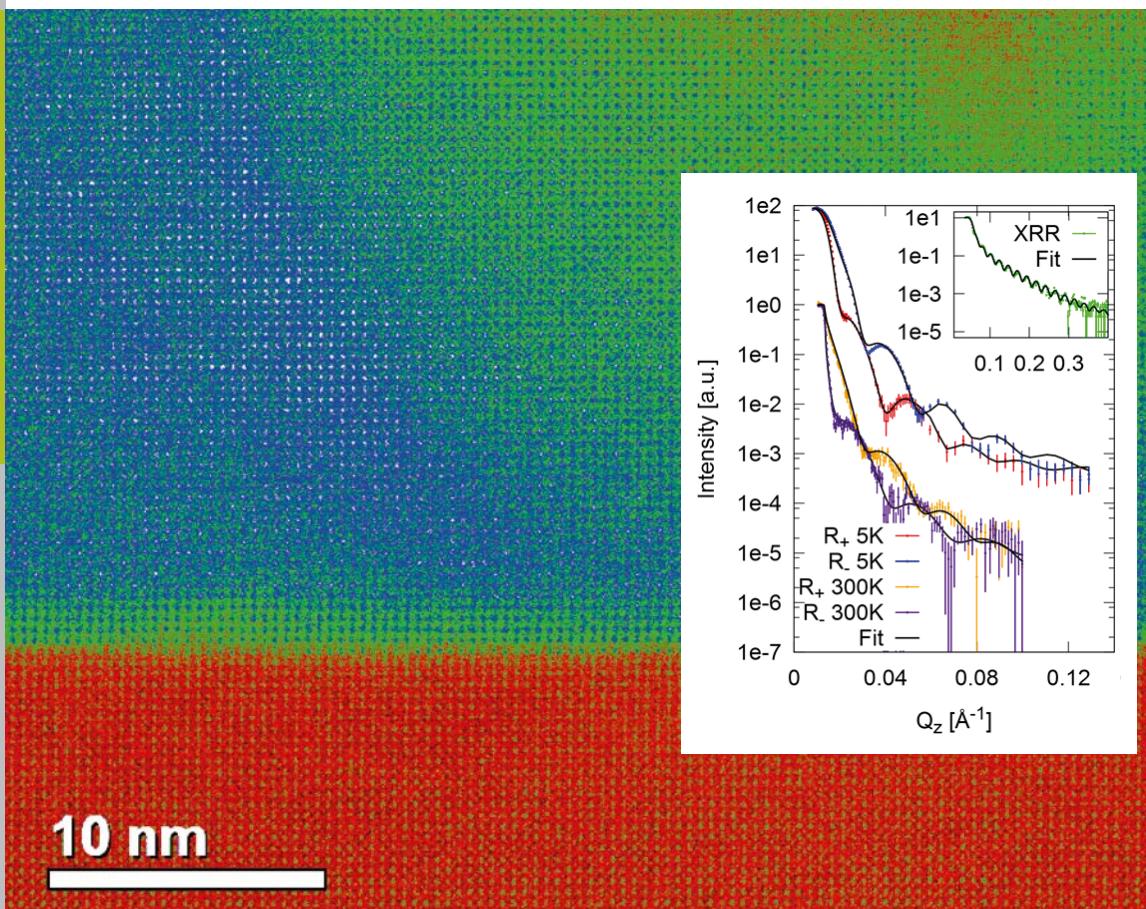


Self-purifying $\text{La}_{2/3}\text{Sr}_{1/3}\text{MnO}_3$ epitaxial films: Observation of surface precipitation of Mn_3O_4 particles for excess Mn ratios

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